OFFPRINT

Understanding large plastic deformation of SiC nanowires at room temperature


EPL, 95 (2011) 63003

Please visit the new website
www.epljournal.org
The Editorial Board invites you to submit your letters to EPL

EPL is a leading international journal publishing original, high-quality Letters in all areas of physics, ranging from condensed matter topics and interdisciplinary research to astrophysics, geophysics, plasma and fusion sciences, including those with application potential.

The high profile of the journal combined with the excellent scientific quality of the articles continue to ensure EPL is an essential resource for its worldwide audience. EPL offers authors global visibility and a great opportunity to share their work with others across the whole of the physics community.

Run by active scientists, for scientists

EPL is reviewed by scientists for scientists, to serve and support the international scientific community. The Editorial Board is a team of active research scientists with an expert understanding of the needs of both authors and researchers.
Six good reasons to publish with EPL

We want to work with you to help gain recognition for your high-quality work through worldwide visibility and high citations.

1. **Quality** – The 40+ Co-Editors, who are experts in their fields, oversee the entire peer-review process, from selection of the referees to making all final acceptance decisions.

2. **Impact Factor** – The 2010 Impact Factor is 2.753; your work will be in the right place to be cited by your peers.

3. **Speed of processing** – We aim to provide you with a quick and efficient service; the median time from acceptance to online publication is 30 days.

4. **High visibility** – All articles are free to read for 30 days from online publication date.

5. **International reach** – Over 2,000 institutions have access to EPL, enabling your work to be read by your peers in 100 countries.

6. **Open Access** – Articles are offered open access for a one-off author payment.

Details on preparing, submitting and tracking the progress of your manuscript from submission to acceptance are available on the EPL submission website **www.epletters.net**.

If you would like further information about our author service or EPL in general, please visit **www.epljournal.org** or e-mail us at info@epljournal.org.

“**We’ve had a very positive experience with EPL, and not only on this occasion. The fact that one can identify an appropriate editor, and the editor is an active scientist in the field, makes a huge difference.**”

**Dr. Ivar Martinv**
Los Alamos National Laboratory, USA.
Visit the EPL website to read the latest articles published in cutting-edge fields of research from across the whole of physics.

Each compilation is led by its own Co-Editor, who is a leading scientist in that field, and who is responsible for overseeing the review process, selecting referees and making publication decisions for every manuscript.

- Graphene
- Liquid Crystals
- High Transition Temperature Superconductors
- Quantum Information Processing & Communication
- Biological & Soft Matter Physics
- Atomic, Molecular & Optical Physics
- Bose–Einstein Condensates & Ultracold Gases
- Metamaterials, Nanostructures & Magnetic Materials
- Mathematical Methods
- Physics of Gases, Plasmas & Electric Fields
- High Energy Nuclear Physics

If you are working on research in any of these areas, the Co-Editors would be delighted to receive your submission. Articles should be submitted via the automated manuscript system at www.epletters.net

If you would like further information about our author service or EPL in general, please visit www.epljournal.org or e-mail us at info@epljournal.org

Image: Ornamental multiplication of space-time figures of temperature transformation rules (adapted from T. S. Bíró and P. Ván 2010 EPL 89 30001; artistic impression by Frédérique Swist).
Understanding large plastic deformation of SiC nanowires at room temperature


Department of Mechanical Engineering, Curtin University - Perth, WA 6845, Australia
School of Physics and Nuclear Energy Engineering, Beihang University - Beijing 100191, China
School of Aeronautics Science and Engineering, Beihang University - Beijing 100191, China
State Key Laboratory of Nonlinear Mechanics (LNM), Institute of Mechanics, Chinese Academy of Sciences - Beijing 100190, China
Department of Manufacturing Engineering and Engineering Management (MEEM), City University of Hong Kong - Kowloon, Hong Kong, China
School of Aerospace, Mechanical and Mechatronic Engineering, University of Sydney Sydney, NSW 2006, Australia
School of Engineering, Brown University - Providence, RI 02912, USA

received 23 June 2011; accepted 26 July 2011
published online 26 August 2011

PACS 31.15.xv – Molecular dynamics and other numerical methods
PACS 62.25.-g – Mechanical properties of nanoscale systems
PACS 62.23.Bj – Nanowires

Abstract – Tensile behaviors of SiC [111] nanowires with various possible microstructures have been investigated by molecular-dynamics simulations. The results show that the large plastic deformation in these nanowires is induced by the anti-parallel sliding of 3C grains along an ultra-thin intergranular amorphous film parallel to the (11\̅1) plane and inclined at an angle of 19.47° with respect to the nanowire axis. The resulting large plastic deformation of SiC nanowires at room temperature is attributed to the stretching, breaking and re-forming of Si–C bonds in the intergranular amorphous film, which is also evident from the sawtooth jumps in the stress-strain response.

Copyright © EPLA, 2011

The mechanical properties of a material critically depend on its intrinsic structures at different length scales. Among these properties, strength and ductility are the two most important ones that are often mutually exclusive and are determined by the physical nature of plastic deformation [1]. For example, materials like ceramics are strong but brittle; most metals, however, are just the opposite. An ideal material should be strong and also ductile. In most real applications, materials with high strength, such as ceramics, usually exhibit poor plasticity. One of the biggest challenges for material scientists is how to improve the deformation capacity of ceramic materials. According to the classical dislocation pile-up theory, the more difficult it is for dislocations to nucleate and slip, the stronger and more brittle a crystalline material becomes. However, this simplistic view breaks down in the case of nano-structured materials due to other deformation mechanisms [2–4]. To fully understand the mechanical response of nano-structured materials to external loading, many experimental studies have been carried out in the last decade. Novel mechanical behaviors have been observed due to their ultra-fine grains and a rather high density of lattice defects in nano-structured materials. Several peculiar deformation mechanisms have been discovered in nano-structured metals such as rotational deformation, deformational twinning and grain boundary-mediated plasticity [5–7]. In contrast to studies on the super-strength of nano-structural metals, there have been relatively few efforts for understanding the properties of nano-structured ceramics. For example, SiC is intrinsically brittle at room temperature, and the lack of ductility or plastic deformation has severely limited its applications. An interesting route to improve the
deformation capacity of SiC and other ceramic materials has been the development of nano-structures [8].

Recently, significant advances have been made since SiC nanowires (NWs) were synthesized. For example, brittle-to-ductile transition and large strain plasticity in SiC NWs were detected with local strain reaching about 2%, which is in stark contrast to the typical strain level of their bulk counterparts (0.1–0.2% or even smaller) [9,10]. Almost at the same time, super-plasticity was found during uniaxial tensile loading of SiC NWs, with local strain exceeding 200%. The observed super-plasticity was assumed to be due to dislocation nucleation, propagation and amorphization developed from cubic (3C) single-crystal segments [11,12]. However, most of the analysis of tensile and bending deformation in SiC only revealed elastic behavior and brittle failure [13–16]. To address this apparent paradox, in this letter, molecular-dynamics simulations have been carried out to analyze the influence of various microstructures on the mechanical behaviors of SiC NWs, with focus on deformation mechanisms that result in the large-plastic-deformation behavior under uniaxial tensile loading.

The SiC NWs synthesized in laboratory usually consist of 3C-structured segments, stacking defects, twins, and an ultra-thin amorphous shell [17,18]. Moreover, an intergranular amorphous film (IAF) with thickness of 0.6 to 0.9 nm between grains was found as a result of aluminium added as sintering aid [19]. Since aluminium is always used to restrict the lateral growth in their synthesis, the IAF is most likely to exist in SiC NWs [20].

Considering that stacking defects occur on close-packed planes like (111) or equivalently for the 3C SiC, and the axis of an individual NW is along the [111] orientation, there are only two relative types of spatial configurations: stacking defects occurring at (111) and (111). The former forms an angle of 19.47° with respect to the [111] orientation and the latter is vertical to the (111) orientation, as illustrated in figs. 1(a) and (b). Stacking defects, twins and IAF can form at either of these angles, resulting in 6 possible spatial structures in SiC NWs, see figs. 1(c) to (e).

To examine the contribution of each structure to the tensile behavior, 8 designed samples are adopted, including 3C single-crystal NW, amorphous shell NW, and the 6 possible structures mentioned above. Every sample has a round cross-section with a diameter of 5 nm and an aspect ratio of length to diameter of about 6:1. To ensure traction-free boundary conditions, a vacuum region of 3 nm is attached on the outside of the lateral surface. Periodic boundary conditions are implemented along all the directions. The 3C crystal segment is generated by an ordered sequence of three basic structure modules of tetrahedral bonding in SiC [21]. The stacking defects are generated by randomly ordered sequences of these modules, while the twins are generated by anti-ordered sequences in comparison with that of the 3C segment. The thickness of stacking defects or twins at an inclination angle of 19.47° is set to 2 nm, while the thickness of their perpendicular counterparts is 5 nm. The IAF is generated by filling amorphous film into a corresponding carved region in a prepared NW. The thickness of IAF is set to 0.75 nm, which lies in the middle of the measured range [19]. The thickness of the amorphous shell and the 3C core are 1 and 1.5 nm, respectively. Dimensions of all the defects are designed by consulting the transmission electron microscope image of individual SiC NW, as shown in fig. 1(f).

A quasi-static loading scheme at 300K is employed to simulate and obtain the tensile deformation and mechanical properties of SiC NWs. The deformation increment along [111] is achieved by two steps. First, a modified isothermal-isobaric ensemble is used to stretch NWs with a strain rate of 0.001 ps^{-1} for 1 ps. This results in a nominal strain of 0.1% at each deformation increment [22]. Then, the axial strain is held and the wire is relaxed for 6 ps via a canonical ensemble [23]. The stress tensor is calculated by a modified virial formula [24]. More details of the numerical techniques were discussed in ref. [25]. An interatomic potential consisting of two-body and three-body covalent interactions is used in molecular-dynamics simulations with a time step of 2 fs by using the DL_POLY2.20 package [23,26]. All the samples are relaxed for 500 ps before stretching.

![Image](300x657 to 368x739)

![Image](379x529 to 417x743)

![Image](423x529 to 460x743)

![Image](508x531 to 548x743)

Fig. 1: (Color online) Illustrations of possible structures of SiC NWs. (a) 19.47° stacking plane, (b) 90° stacking plane, (c) schematic diagrams of stacking defects (SD) at inclination angles of 19.47° and 90° to the axis, (d) sketched map of twins (TW), (e) patterns of IAF and (f) an individual SiC NW adapted from ref. [11]. Here, darker strips and lighter regions correspond to SD-90° and 3C segments, respectively. The thin black slashes in 3C segments indicate defects with an inclination angle of 19.47°, as illustrated in (c) to (e).
Understanding large plastic deformation of SiC nanowires at room temperature

The typical stress-strain responses of SiC NWs containing stacking defects, twins and amorphous shell are shown in fig. 2. In comparison with NWs containing stacking defects or amorphous shell, the 3C single-crystal NW has the highest Young’s modulus, strength and elongation of 289 GPa, 28.5 GPa and 10.7%, respectively. NWs with stacking defects at 19.47° result in weaker modulus, strength and elongation than that of their perpendicular counterparts. Furthermore, the amorphous shell NW shows the lowest modulus and strength of 158 and 12.4 GPa, respectively. In a recent study, it was shown that the brittle-to-ductile transition could be triggered by amorphous shell at temperature beyond 700 K [27]. Here, similar results were obtained at the room temperature, and the brittle failure occurs at a strain of 9.5% without plastic behavior. It can be concluded that, therefore, none of these structures contributes to the large plastic deformation at room temperature.

The IAF shows a significant impact on the tensile behavior, as shown in fig. 3(a). The IAF-90° is not beneficial to plasticity (here, IAF-90° indicates the IAF being vertical or at an angle of 90° to the axis, and similar abbreviations are used hereafter). It induces brittle failure just at the location of IAF as soon as the strain reaches 4.5%; see inset in fig. 3(a). This elongation is 53.6% smaller than the corresponding value of 9.7%, for NWs with stacking defects perpendicular to the axis (SD-90°). In contrast, IAF-19.47° shows qualitatively different behaviors. Specifically, Young’s modulus drops by 7.3% from 275 to 255 GPa in comparison with that of NWs with SD-90°. The strength also decreases by 16.5% from 12.1 to 10.1 GPa. However, the plastic behavior occurs even before the tensile strength (i.e., point A in fig. 3(a) with strain of 4.2%) is reached. Unloading from point A shows that a strain of 0.3% remains after the external force is completely removed. Unloading from a strain level of 4.3% (point B in fig. 3(a)) leads to a residual strain of 1.6%, indicating the occurrence of large plastic deformation.

The plastic deformation is achieved through the anti-parallel sliding of two 3C grains along (111) plane, as shown in fig. 3(b). The tensile response shows sawtooth jumps that result from stretching, breaking and re-forming of Si–C bonds in the IAF, see figs. 3(c) to (e). Specifically, as strain increases from 8.5% to 9.6%, stretching of Si–C bonds in the IAF dominates the deformation (from C to D in fig. 3(a)). As they reach their tensile limit, the stretched bonds break and lead to an abrupt stress drop until a new bond forms (from D to E in fig. 3(a)). Thus, the anti-parallel sliding of the two 3C grains results...
in repeated sawtooth jumps. It is worth noting that the local unloading curve at point D is consistent with the corresponding loading curve at point C. That is, the stage of C to D of the sawtooth originates from the elastic stretching of Si–C bonds in IAF. Furthermore, the slope of the upswing portion of each sawtooth (from C to D) is similar to that of the elastic regime of the stress-strain curve, indicating that the mechanical properties of SiC NWs are determined by the stretching limit of Si–C bonds in IAF. Repetition of this sawtooth jumping behavior of the stress-strain response produces a plastic elongation of 20.9% until brittle failure occurs in the right 3C grain; see fig. 3(f). The final elongation is 4.6 times of the corresponding value of 4.5% for the IAF-90°.

Among all possible structures, IAF-19.47° shows the lowest tensile strength. It is known that the mechanical behaviors of a material are closely related to its weaker section. The tensile behaviors of a wire are exclusively determined by the shearing deformation along the IAF-19.47° even if such a wire consists of all the possible structures. Other structures give little contribution to the tensile strain because they are too strong to be deformed and their corresponding strengths cannot be reached.

A proper understanding of the large plastic deformation in SiC NWs can be given as follows. In the local region with an aspect ratio of 6:1, each IAF-19.47° shows a plastic elongation of 20.9%. In a cubic crystal, there are 4 close-packed planes, (111), (111), (111) and (111). The former 3 form an angle of 19.47° with respect to the [111] orientation, while the latter is perpendicular to the axis. Therefore, there are 3 equivalent spatial possibilities for an IAF to form an inclination angle of 19.47° with respect to the [111] orientation and each of them has equal tendency to contribute to the plastic behavior. However, the interaction among a higher density of IAFs and their effect on plastic deformation in SiC NWs is still an open challenge. Further, IAFs with the higher density and various spatial locations may converge to form a more complicated IAF network, known as amorphous grain boundaries, which may also contribute to local plasticity. Actually, the amorphous grain boundaries have already been proved to have significant impact on the plastic behavior of nano-structured SiC. There are extensive literatures focusing on the role of amorphous grain boundaries and the corresponding plastic behaviors have already been well analysed [28,29].

In summary, a comprehensive analysis via molecular-dynamics simulations has been conducted to investigate the effects of possible microstructures on the tensile behavior of SiC NWs. The results show that only those structures with IAFs parallel to (111) and inclined at an angle of 19.47° with respect to the [111] orientation lead to large plastic deformation due to the anti-parallel sliding of 3C grains along the IAFs. The resulting plastic deformation can be clearly seen through sawtooth jumps in the stress-strain response, and its micro-mechanism is attributed to the stretching, breaking and re-forming of Si–C bonds in the IAF. It should be pointed out that this mechanism differs from the conventional plastic deformation in metals, which is usually associated with the generation and propagation of dislocations. The present study contributes to the understanding of large plastic deformation of nano-structured ceramics, especially for SiC NWs at room temperature. This work also provides guidance on the microstructural design for high-plastic ceramics with tailored mechanical properties.

***

This work was supported by the Australian Research Council (Grant No. DP0985450), the National Natural Science Foundation of China (Grant Nos. 10172090, 10932011, 10972218 and 11021262) and the National Basic Research Program of China (2007CB814803). Computations were performed on computer clusters at the CNIC supercomputing Center, iVEC through the use of advanced computing resources located at iVEC@ARRC and on parallel clusters acquired through the WCU program in the School of Mechanical and Aerospace Engineering at SNU.

REFERENCES


63003-p4
Understanding large plastic deformation of SiC nanowires at room temperature


